



4 CHANNEL LOW CAPACITANCE TVS DIODE ARRAY

Product Summary

V _{BR} (Min)	IPP (Max)	Сі/о (тур)
5.0V	4.0A	0.28pF

Description

The D3V3XA4B10LP is a high-performance device suitable for protecting four high speed I/Os. This device is assembled in U-DFN2510-10 and U-DFN2510-10 (Type CJ) packages and has high ESD surge capability, low ESD clamping voltage and ultra-low capacitance.

Applications

Typically used at high-speed ports such as HDMI2.1, USB 3.0, USB 3.1, Serial ATA, Display port.

Features

- Clamping Voltage: 9.4V at 16A TLP
- IEC 61000-4-2 (ESD): Air ±12kV, Contact ±12kV
- IEC 61000-4-5 (Lightning): 4.0A (8/20µs)
- 4 Channels of ESD Protection
- Ultra-Low Channel Input Capacitance of 0.35pF Max
- TLP Dynamic Resistance: 0.39Ω
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.

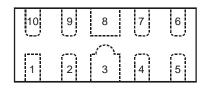
https://www.diodes.com/quality/product-definitions/

Mechanical Data

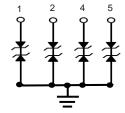
- Case: U-DFN2510-10
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: NiPdAu over Copper Leadframe (Lead Free Plating).
 Solderable per MIL-STD-202, Method 208 (e4)
- Weight: 0.038 grams (Approximate)

U-DFN2510-10 and U-DFN2510-10 (Type CJ)

Pin #	Description
1, 2, 4, 5	I/O
6, 7, 9, 10	No Connection
3, 8	Vss



Pin Description (Top View)



Device Schematic

Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
D3V3XA4B10LP-7	Standard	ZS1	7	8	3,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information

ZS1 YM

ZS1 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: H = 2020) M = Month (ex: 9 = September)

ZS1 YWX

ZS1 = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 0 = 2020) W = Week

(ex: a=Week 27; z Represents Week 52 and 53) X = Internal Code (ex: U=Monday)

Date Code Kev for YM

Date Code Rey IC												
Year	2018	2019	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	F	G	Н		J	K	L	М	N	0	Р	R
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec

Date Code Key for YWX

Year	2018	2019	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	8	9	0	1	2	3	4	5	6	7	8	9
Week	Week 1-26			27-52				53				
Code	A-Z				a-z			Z				
Internal Code	Sun		Mon		Гие	We	d	Thu		Fri		Sat
Code	Т		U		V	W		Χ		Υ		Z

Maximum Ratings (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	Conditions
Peak Pulse Current, per IEC 61000-4-5	lpp	4.0	Α	I/O to Vss, 8/20µs
Peak Pulse Power, per IEC 61000-4-5	P _{PP}	24	W	I/O to V _{SS} , 8/20µs
ESD Protection – Contact Discharge, per IEC 61000-4-2	Vesd_contact	±12	kV	I/O to Vss
ESD Protection – Air Discharge, per IEC 61000-4-2	V _{ESD_AIR}	±12	kV	I/O to Vss

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation Typical (Note 5)	P _D	350	mW
Thermal Resistance, Junction to Ambient Typical (Note 5)	R _θ JA	360	°C/W
Operating and Storage Temperature Range	T _J ,T _{STG}	-55 to +150	°C

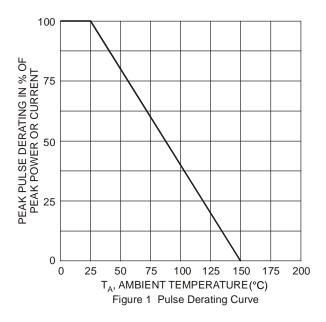
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

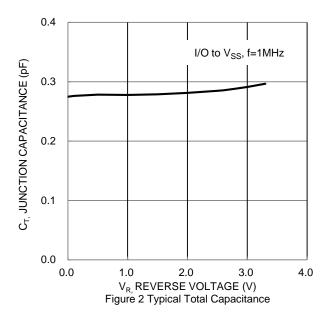
Characteristic	Symbol	Min	Тур	Max	Unit	Test Conditions
Reverse Working Voltage	VRWM	_	_	3.3	V	_
Reverse Current	IR	_	_	1.0	μA	V _R = 3.3V, I/O to Vss
Reverse Breakdown Voltage	V_{BR}	5.0	_	9.0	V	I _R = 1mA, I/O to V _{SS}
Clamping Voltage (Note 6)	Vc	_	9.4	_	V	TLP, 16A, tp = 100ns, I/O to Vss
Dynamic Reverse Resistance	Rdif	_	0.39	_	Ω	TLP, 10A, tp = 100ns, I/O to Vss
Channel Input Capacitance	CI/O	_	0.28	0.35	pF	V _{I/O} = 0V, V _{SS} = 0V, f = 1MHz

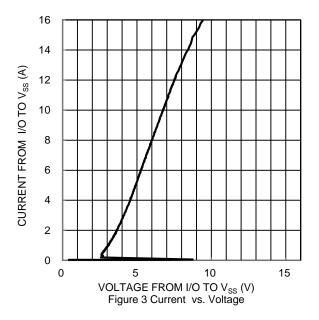
Notes: 5. Device mounted on FR-4 PCB pad layout (2oz copper) as shown on Diodes Incorporated's suggested pad layout, which can be found on our website at http://www.diodes.com/package-outlines.html.

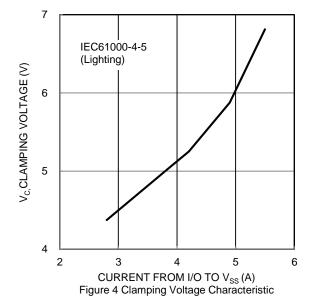
^{6.} Clamping voltage value is based on a TLP model. TLP conditions: Z_0 =50 Ω , t_P = 100ns, averaging window; t1=70ns to t2=90ns









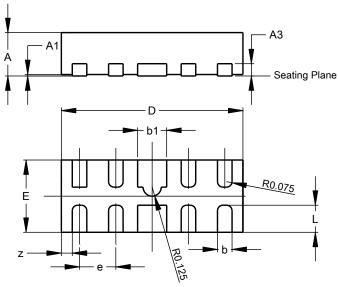




Package Outline Dimensions

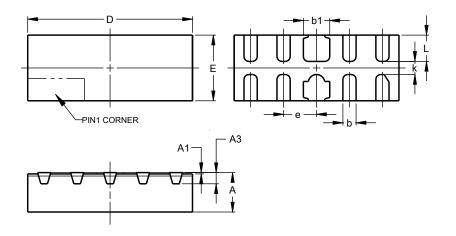
Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN2510-10



	U-DFN2510-10						
Dim	Min	Max	Тур				
Α	0.545	0.605	0.575				
A 1	0.00	0.05	0.03				
А3	-	-	0.13				
b	0.15	0.25	0.20				
b1	0.35	0.45	0.40				
D	2.450	2.575	2.500				
е	-	1	0.50				
Е	0.950	1.075	1.000				
L	0.325	0.425	0.375				
z	-	-	0.150				
All	All Dimensions in mm						

U-DFN2510-10 (Type CJ)



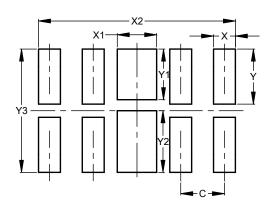
	U-DFN2510-10 (Type CJ)						
Dim	Min	Min Max					
Α	0.545	0.605					
A 1	0.00	0.05					
А3		0.152REF					
b	0.150	0.250					
b1	0.350	0.450					
D	2.450	2.575					
Е	0.950	1.075					
е			0.500				
E	0.950	1.075	1.000				
L	0.350						
k	k 0.200REF						
All	Dimens	ions in m	m				



Suggested Pad Layout

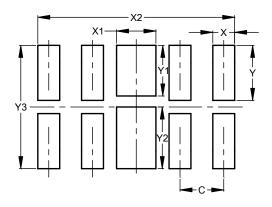
 $\label{prop:lease} Please see \ http://www.diodes.com/package-outlines.html \ for \ the \ latest \ version.$

U-DFN2510-10



Dimensions	Value (in mm)
С	0.500
Х	0.250
X1	0.450
X2	2.250
Υ	0.625
Y1	0.575
Y2	0.700
Y3	1.400

U-DFN2510-10 (Type CJ)



Dimensions	Value (in mm)
С	0.500
Х	0.250
X1	0.450
X2	2.250
Υ	0.625
Y1	0.575
Y2	0.700
Y3	1.400



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